High Performance Schottky Rectifiers, 120 A

HALF-PAK (D-67)

FEATURES

- 125 °C T_J operation (V_R < 5 V)
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

Pb-free

RoHS COMPLIANT

DESCRIPTION

The VS-125NQ.. high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

PRODUCT SUMMARY	
$I_{F(AV)}$	120 A
V_R	15 V
Package	HALF-PAK (D-67)
Circuit	Single diode

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	120	A
V_{RRM}		15	V
I_{FSM}	t_p = 5 µs sine	10 800	A
V_F	120 A_{pk}, T_J = 125 °C	0.37	V
T_J	Range	-55 to 125	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-125NQ015PbF	UNITS
Maximum DC reverse voltage	V_R	15	V
Maximum working peak reverse voltage	V_{RWM}	25	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	$I_{F(AV)}$	50 % duty cycle at T_C = 74 °C, rectangular waveform		120	A
Maximum peak one cycle non-repetitive surge current See fig. 7	I_{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	10 800	
		10 ms sine or 6 ms rect. pulse		1700	
Non-repetitive avalanche energy	E_{AS}	T_J = 25 °C, I_{AS} = 5 A, L = 1 mH		12	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		2	A

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop per leg See fig. 1	V_{FM} (1)	120 A	T_J = 25 °C	0.43	V
		240 A		0.58	
		120 A	T_J = 75 °C	0.37	
		240 A		0.52	
Maximum reverse leakage current per leg See fig. 2	I_{RM} (1)	T_J = 25 °C	V_R = Rated V_R	40	mA
		T_J = 100 °C		2000	
Maximum junction capacitance	C_T	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		7700	pF
Typical series inductance	L_S	From top of terminal hole to mounting plane		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/µs

Note

(1) Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range		T_J		-55 to 125	°C
Maximum storage temperature range		T_{Stg}		-55 to 150	
Maximum thermal resistance, junction to case		R_{thJC}	DC operation See fig. 4	0.38	°C/W
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.05	
Approximate weight				30	g
				1.06	oz.
Mounting torque	minimum		Non-lubricated threads	3 (26.5)	N · m (lbf · in)
	maximum			4 (35.4)	
Terminal torque	minimum			3.4 (30)	
	maximum			5 (44.2)	
Case style				HALF-PAK module	

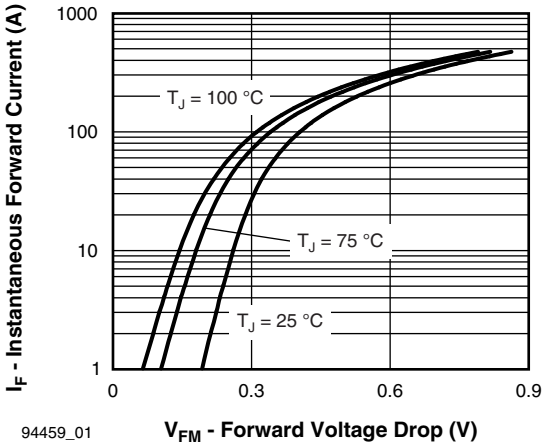


Fig. 1 - Maximum Forward Voltage Drop Characteristics

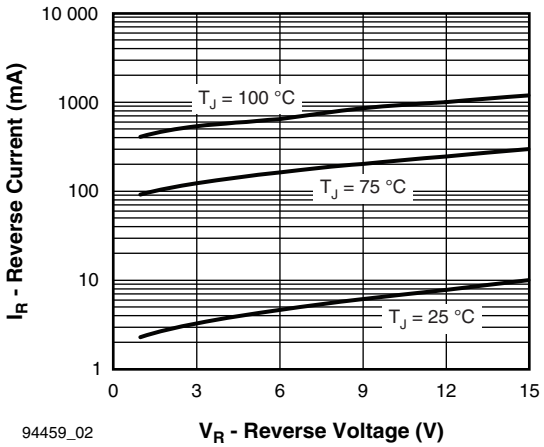


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

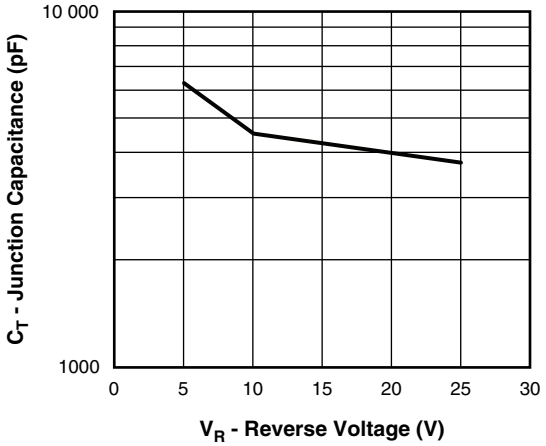


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

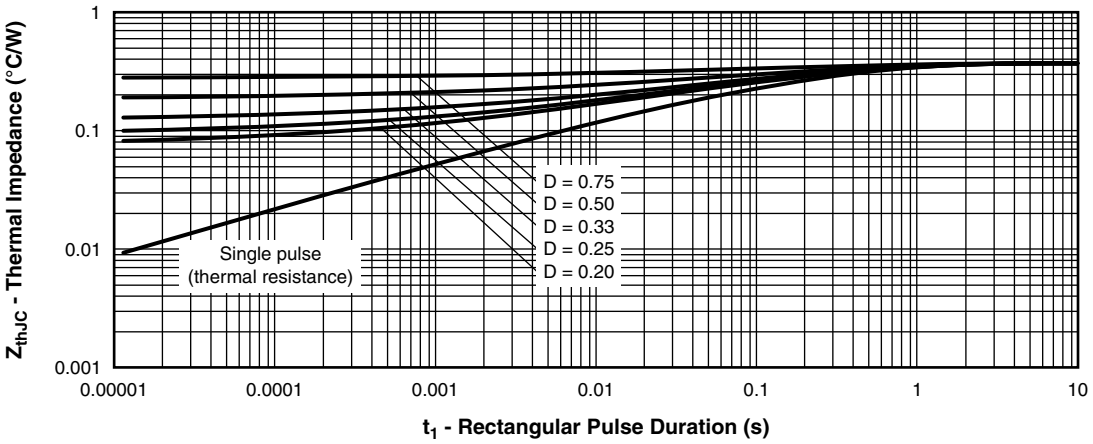


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

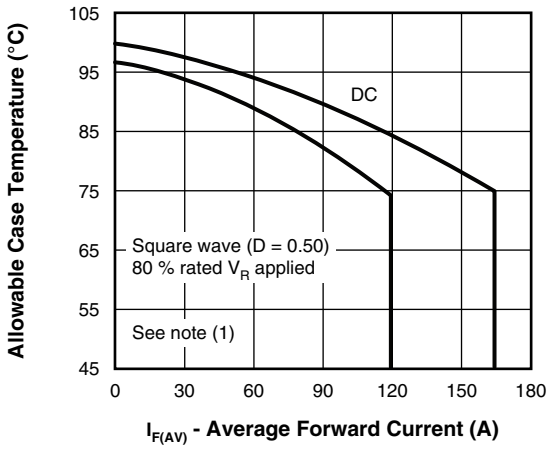


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

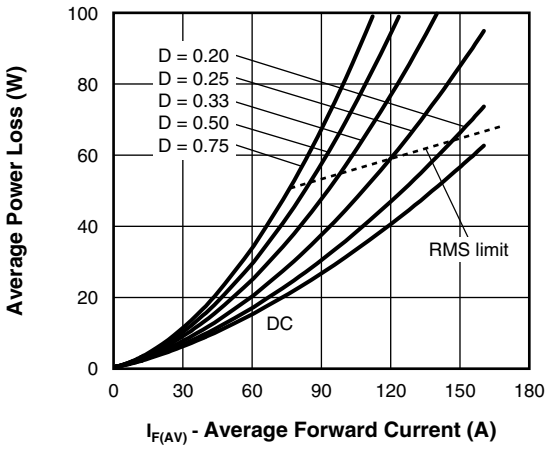


Fig. 6 - Forward Power Loss Characteristics

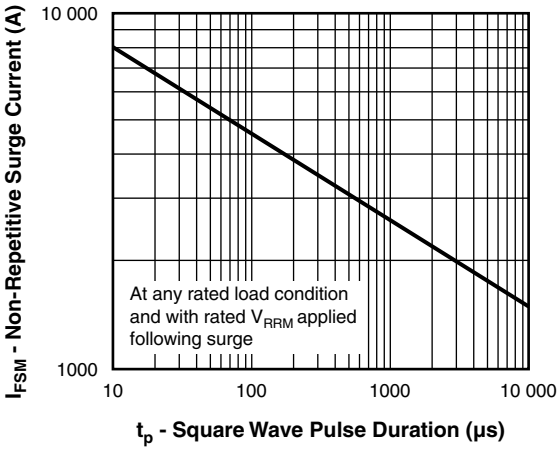


Fig. 7 - Maximum Non-Repetitive Surge Current

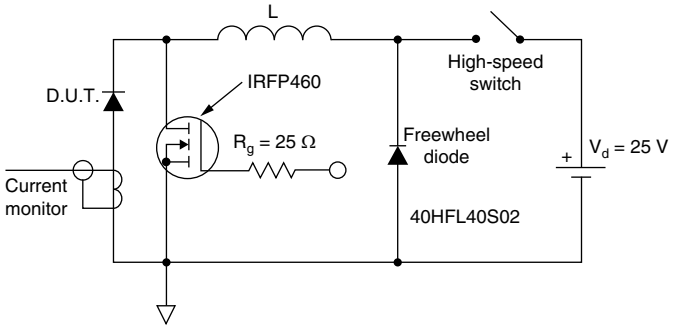


Fig. 8 - Unclamped Inductive Test Circuit

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}$/D) (see fig. 6);
Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R

ORDERING INFORMATION TABLE

Device code

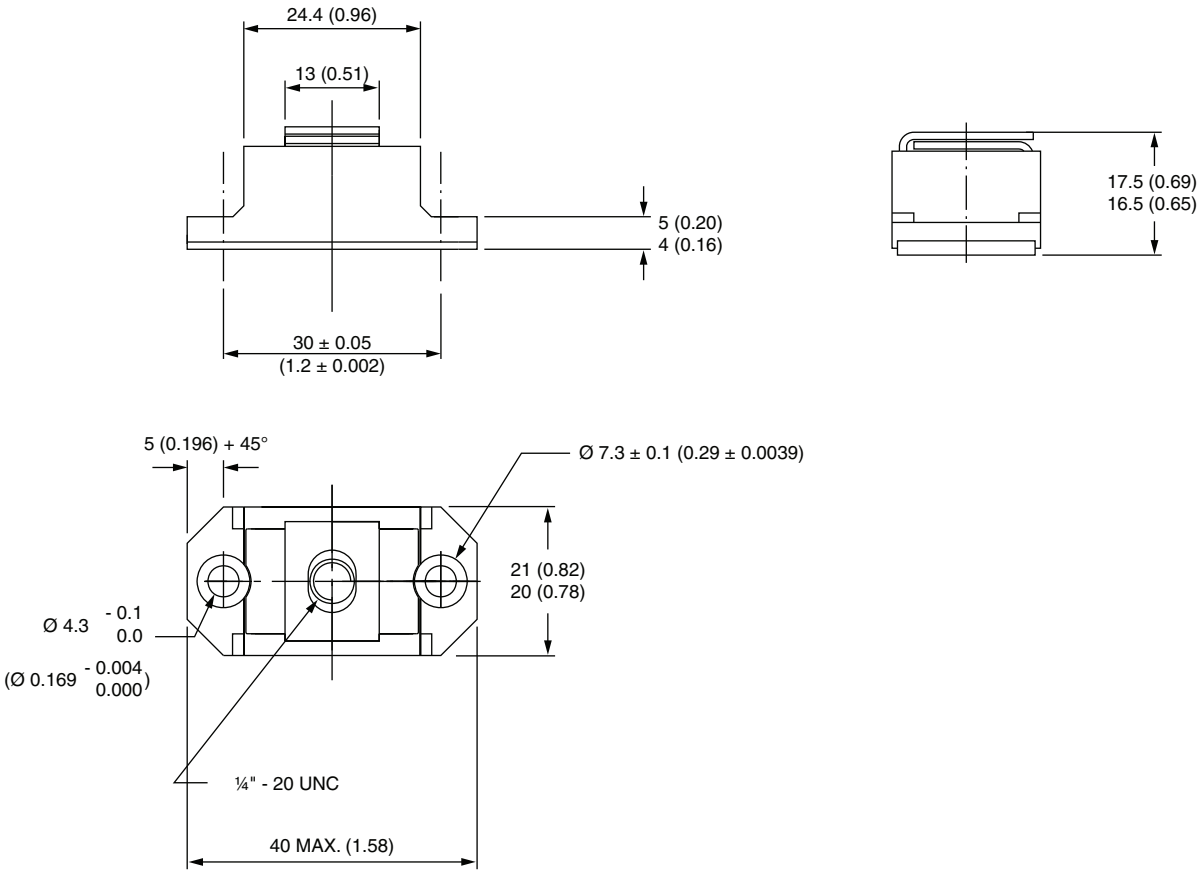
VS-	12	5	N	Q	015	PbF
1	2	3	4	5	6	7

1	-	Vishay Semiconductors product
2	-	Average current rating (x 10)
3	-	Product silicon identification
4	-	N = Not isolated
5	-	Q = Schottky rectifier diode
6	-	Voltage rating (015 = 15 V)
7	-	Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95020

D-67 HALF-PAK

DIMENSIONS in millimeters (inches)



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